NSN 5961-01-165-5163

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-165-5163

Inclosure Material:

Metal

Overall Length:

0.508 inches

Overall Height:

0.120 inches

Overall Width:

0.188 inches

Internal Configuration:

Junction contact

Mounting Method:

Press fit

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

15.0 collector to emitter voltage/static/base open and 20.0 collector to base voltage/static/emitter open and 3.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

30.00 milliamperes source cutoff current

Power Rating Per Characteristic:

180.0 milliwatts small-signal input power, common-collector absolute

Transfer Ratio:

250.0 static forward current transfer ratio, common-emitter

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0